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[Vishay Semiconductor/Diodes Division](#)
[BYVB32-100-E3/81](#)

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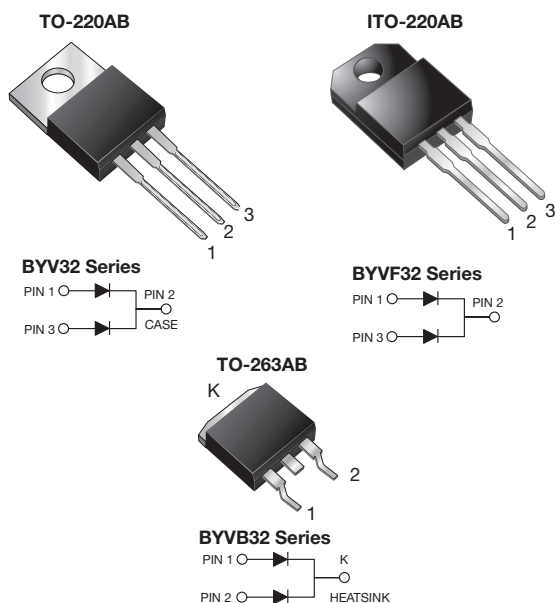


www.vishay.com

BYV32-xxx, BYVF32-xxx, BYVB32-xxx

Vishay General Semiconductor

Dual Common-Cathode Ultrafast Rectifier



FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	18 A
V_{RRM}	50 V to 200 V
I_{FSM}	150 A
t_{rr}	25 ns
V_F	0.85 V
T_J max.	150 °C
Package	TO-220AB, ITO-220AB, TO-263AB
Diode variations	Common cathode

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_C = 125$ °C	$I_{F(AV)}$	18				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150				A
Operating storage and temperature range	T_J, T_{STG}	-65 to +150				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1$ min	V_{AC}	1500				V



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum instantaneous forward voltage per diode	I _F = 20 A	T _J = 25 °C	V _F ⁽¹⁾	1.15				V
	I _F = 5.0 A	T _J = 100 °C		0.85				
Maximum DC reverse current per diode at rated DC blocking voltage		T _J = 25 °C	I _R	10				μA
		T _J = 100 °C		600				
Maximum reverse recovery time per diode	I _F = 1 A, V _R = 30 V dI/dt = 100 A/μs, I _{rr} = 10 % I _{RM}		t _{rr}	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz		C _J	45				pF

Note

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYV	BYVF	BYVB	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.6	5.0	1.6	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	BYV32-200HE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200HE3/45 ⁽¹⁾	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

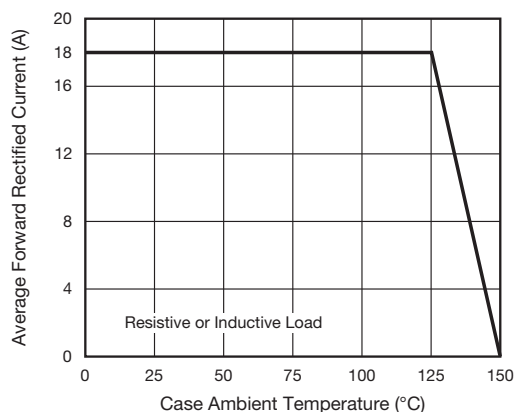


Fig. 1 - Forward Current Derating Curve

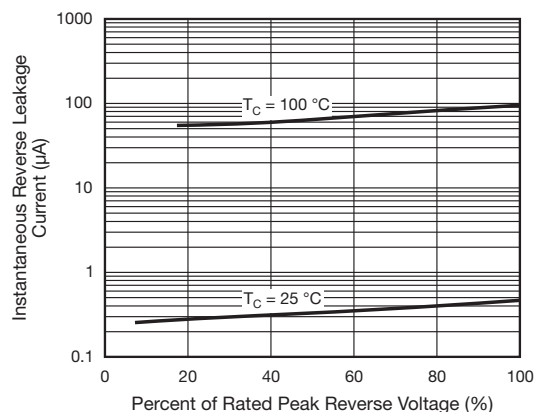


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

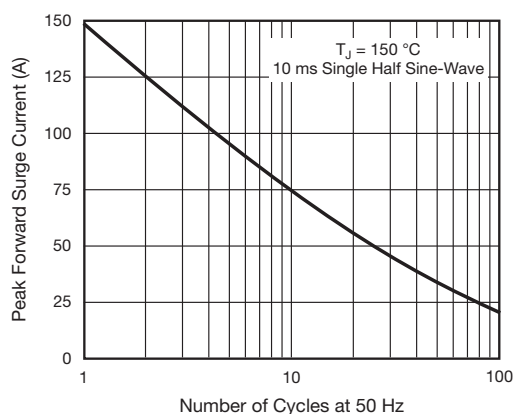


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

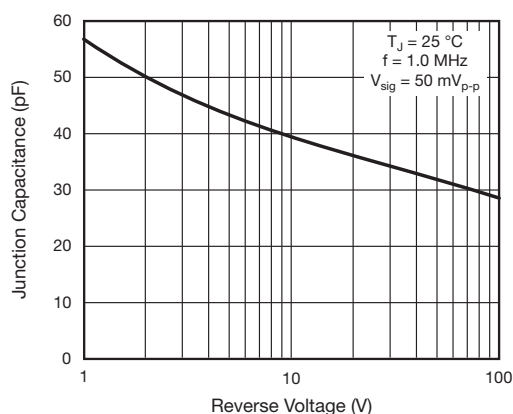


Fig. 5 - Typical Junction Capacitance Per Diode

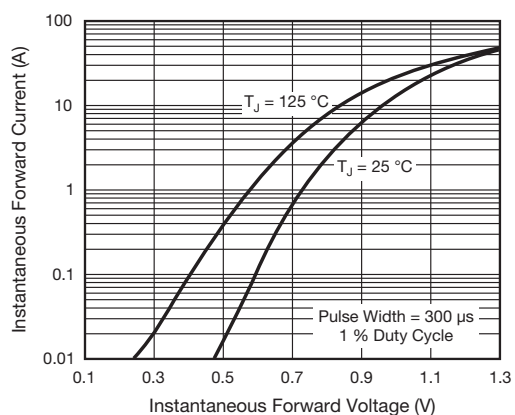


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

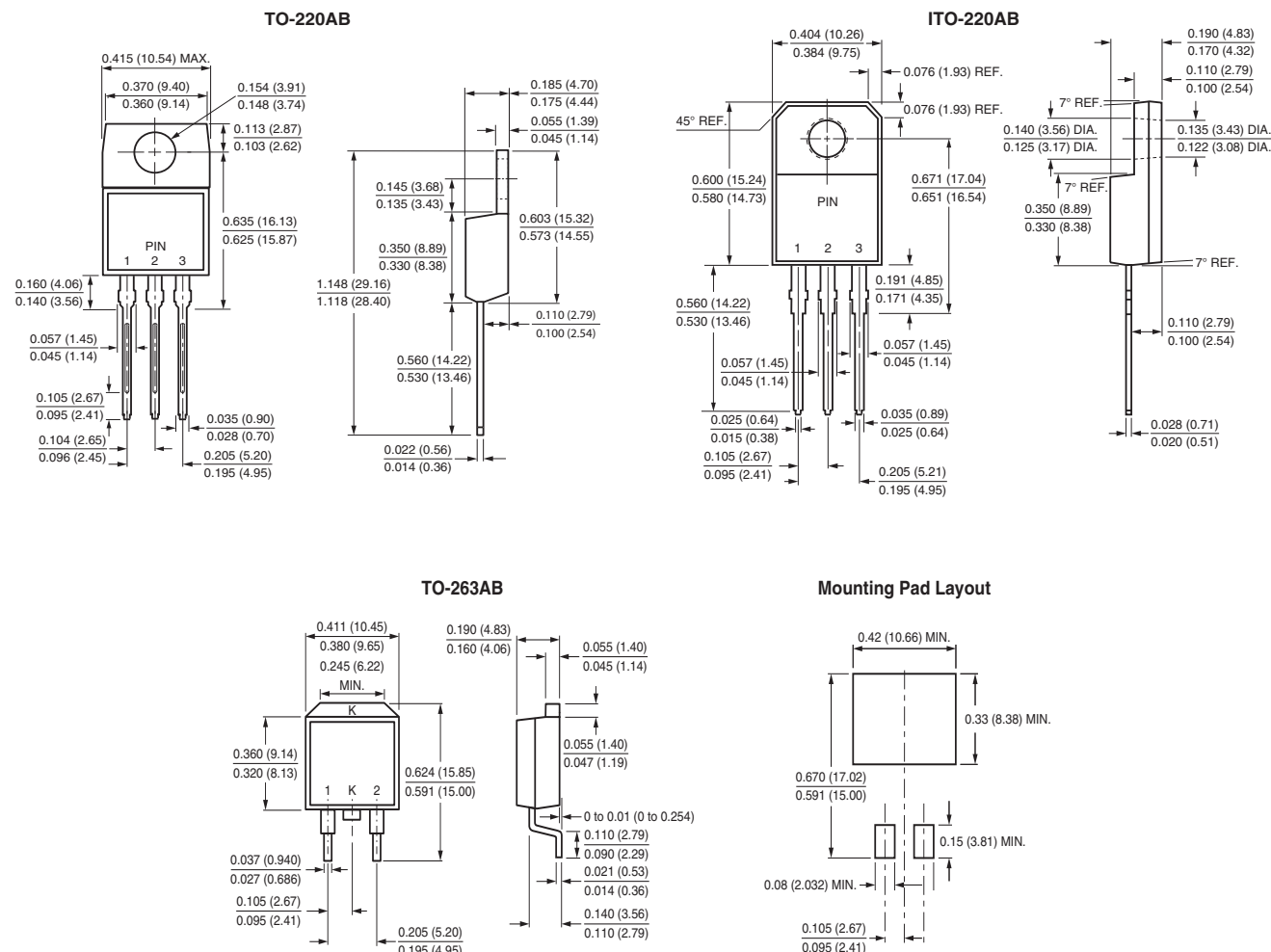


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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